RENESAS

HD74HCT245

Octal Bus Transceivers (with 3-state outputs)

REJ03D0665–0200 (Previous ADE-205-554) Rev.2.00 Mar 30, 2006

Description

This device has an active low enable input \overline{G} and a direction control input (DIR). When DIR is high, data flows from the A inputs to the B outputs. When DIR is low, data flows from the B inputs to the A outputs. The HD74HCT245 transfers true data from one bus to the other.

This device does not have schmitt trigger inputs.

Features

- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation: t_{pd} (A to Y) = 12 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 4.5$ to 5.5 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code Package (Previous Code) Abbreviation		Taping Abbreviation (Quantity)	
HD74HC245P	DILP-20 pin	PRDP0020AC-B (DP-20NEV)	Ρ	_	
HD74HC245FPEL	SOP-20 pin (JEITA)	PRSP0020DD-B (FP-20DAV)	FP	EL (2,000 pcs/reel)	
HD74HC245RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)	
HD74HC245TELL	TSSOP-20 pin	PTSP0020JB-A (TTP-20DAV)	т	ELL (2,000 pcs/reel)	

Note: Please consult the sales office for the above package availability.

Function Table

Enable G	Direction Control DIR	Operation		
L	L	B data to A bus		
L	Н	A data to B bus		
Н	X	Isolation		

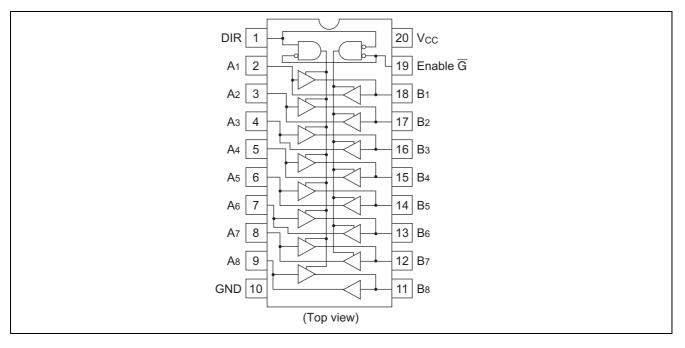
H : high level

L : low level

X : irrelevant



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	V _{IN} , V _{OUT}	-0.5 to V _{CC} +0.5	V
Input / Output diode current	Ι _{ικ} , Ι _{οκ}	±20	mA
Output current	Ι _Ο	±35	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±75	mA
Power dissipation	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

ltem	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	4.5 to 5.5	V	
Input / Output voltage	Vin, Vout	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
Input rise / fall time ^{*1}	t _r , t _f	0 to 500	ns	V _{CC} = 4.5 V

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



Electrical Characteristics

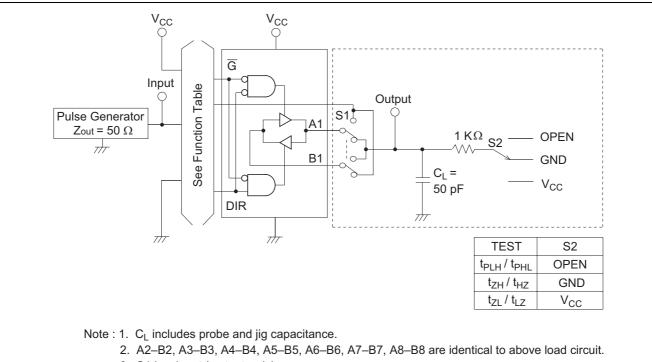
ltem	Symbol	V _{cc} (V)	Ta = 25°C			Ta = -40 to+85°C		Unit	Test Conditions	
			Min	Тур	Max	Min	Max	Unit	Test conditions	
Input voltage	V _{IH}	4.5 to 5.5	2.0		_	2.0	—	V		
	VIL	4.5 to 5.5	_		0.8		0.8	V		
Output voltage	V _{OH}	4.5	4.4			4.4	—	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{OH} = -20 μA
		4.5	4.18		_	4.13	—			I _{ОН} = —6 mA
	V _{OL}	4.5	_		0.1		0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{OL} = 20 μA
		4.5	_		0.26		0.33			I _{OL} = 6 mA
Off-state output	l _{oz}	5.5	_	_	±0.5	_	±5.0	μA	$Vin = V_{IH} \text{ or } V_{IL},$	
current									Vout = V_{CC} or GND	
Input current	lin	5.5		_	±0.1		±1.0	μA	$Vin = V_{CC} \text{ or } GND$	
Quiescent current	Icc	5.5		_	4.0	—	40	μΑ	Vin = V_{CC} or GND, lout = 0 μ A	

Switching Characteristics

 $(C_L = 50 \text{ pF}, \text{ Input } t_r = t_f = 6 \text{ ns})$

ltem	Symbol	V _{cc} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
nem			Min	Тур	Max	Min	Max	Onit	
Propagation delay time	t _{PLH}	4.5	_	11	22	—	28	ns	
	t _{PHL}	4.5	_	13	22	—	28		
Output enable time	t _{ZL}	4.5	_	17	30	—	38	ns	
	t _{ZH}	4.5	_	14	30	—	38		
Output disable time	t _{LZ}	4.5	_	20	30	—	38	ns	
	t _{HZ}	4.5	_	22	30	—	38		
Output rise/fall time	t _{TLH}	4.5	_	4	12	—	15	ns	
	t_{THL}								
Input capacitance	Cin	_	l	5	10	_	10	рF	

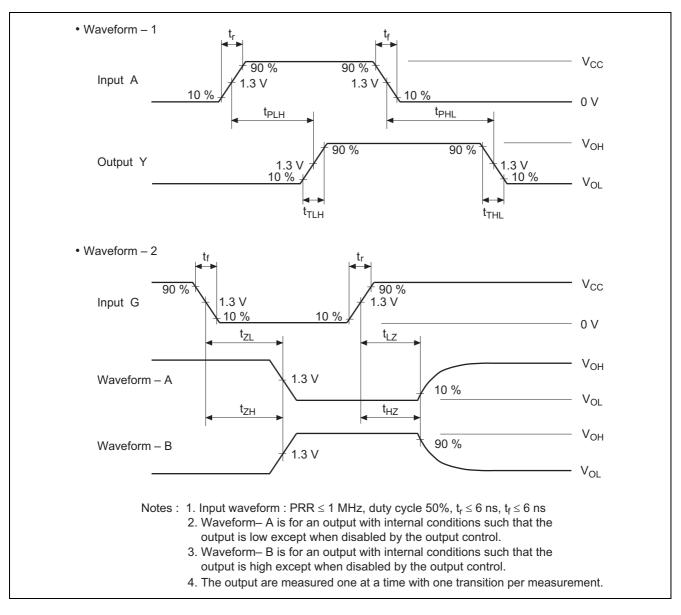
Test Circuit



3. S1 is a input / output swich.

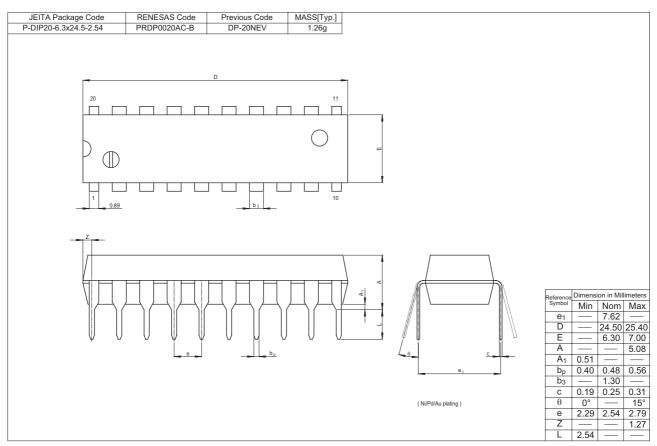


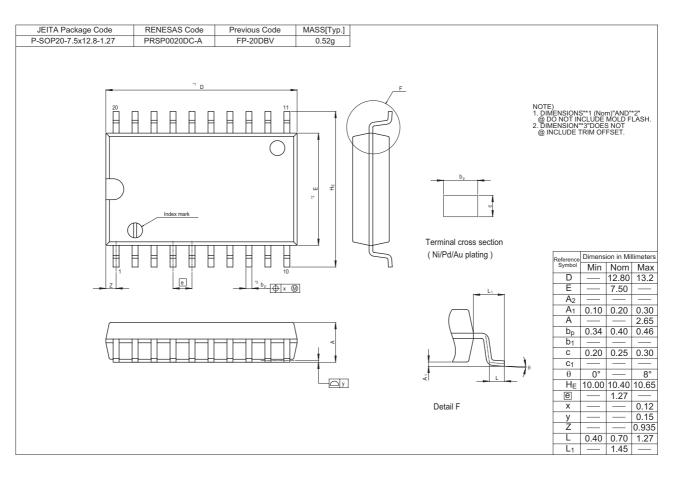
Waveforms





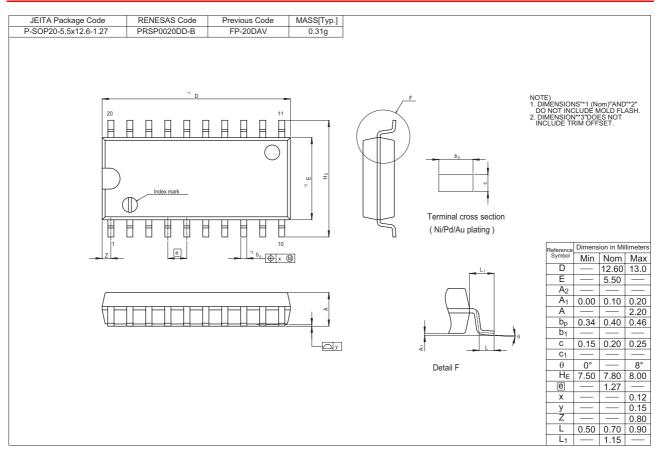
Package Dimensions

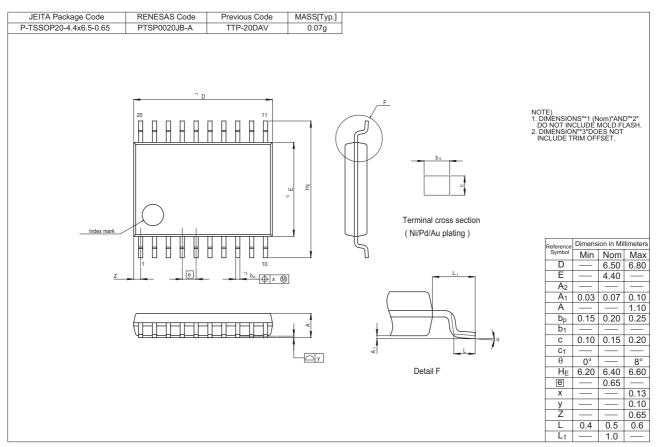






HD74HCT245







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